



2SK4065

N-Channel Power MOSFET 75V, 100A, 6mΩ, TO-263-2L

ON Semiconductor®

<http://onsemi.com>

Features

- ON-resistance $R_{DS(on)1}=4.6m\Omega$ (typ.)
- 4V drive
- Input capacitance $C_{iss}=12200pF$ (typ.)

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		75	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		100	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	400	A
Allowable Power Dissipation	P_D		1.65	W
		$T_c=25^\circ C$	90	W
Channel Temperature	T_{ch}		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$
Avalanche Energy (Single Pulse) *1	E_{AS}		735	mJ
Avalanche Current *2	I_{AV}		70	A

Note : *1 $V_{DD}=30V$, $L=200\mu H$, $I_{AV}=70A$ (Fig.1)

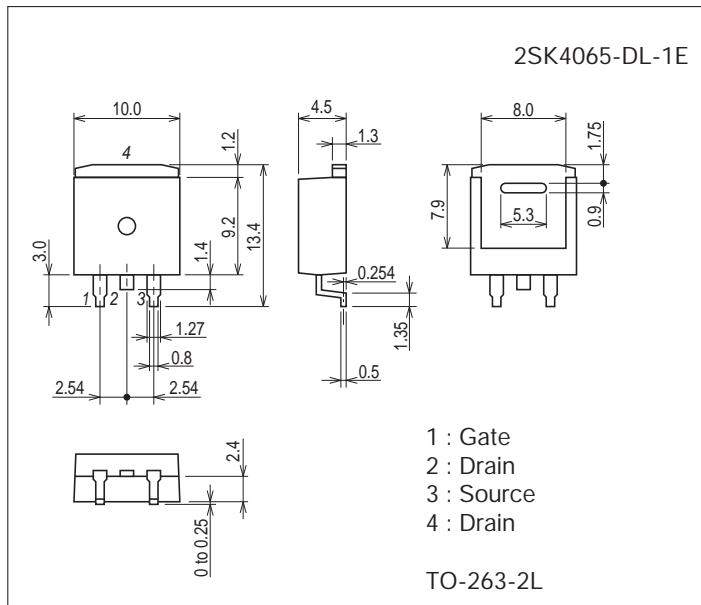
*2 $L \leq 200\mu H$, single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

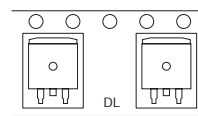
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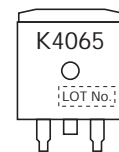
Product & Package Information

- Package : TO-263-2L
- JEITA, JEDEC : SC-83, TO-263
- Minimum Packing Quantity : 800 pcs./reel

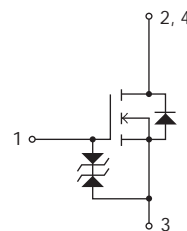
Packing Type: DL



Marking



Electrical Connection



2SK4065

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	75			V
Zero-Gate Voltage Drain Current	IDSS	VDS=75V, VGS=0V			1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	VDS=10V, ID=50A	47	78		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=50A, VGS=10V		4.6	6.0	mΩ
	RDS(on)2	ID=50A, VGS=4V		5.7	8.0	mΩ
Input Capacitance	Ciss	VDS=20V, f=1MHz		12200		pF
Output Capacitance	Coss			950		pF
Reverse Transfer Capacitance	Crss			730		pF
Turn-ON Delay Time	td(on)		See Fig.2		80	
Rise Time	tr			460		ns
Turn-OFF Delay Time	td(off)			930		ns
Fall Time	tf			640		ns
Total Gate Charge	Qg	VDS=35V, VGS=10V, ID=100A			220	
Gate-to-Source Charge	Qgs			40		nC
Gate-to-Drain "Miller" Charge	Qgd			50		nC
Diode Forward Voltage	VSD	IS=100A, VGS=0V		0.9	1.2	V

Fig.1 Avalanche Resistance Test Circuit

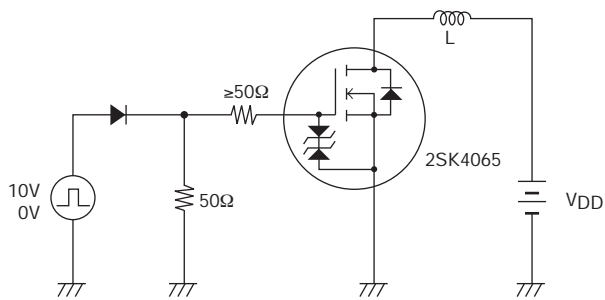
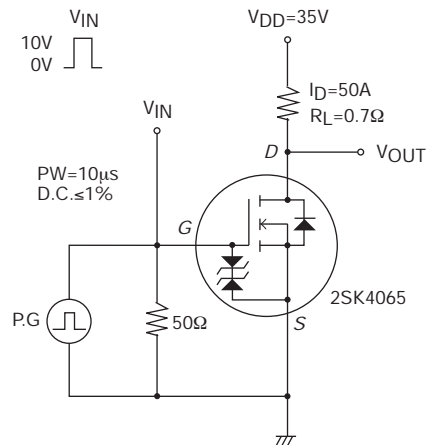
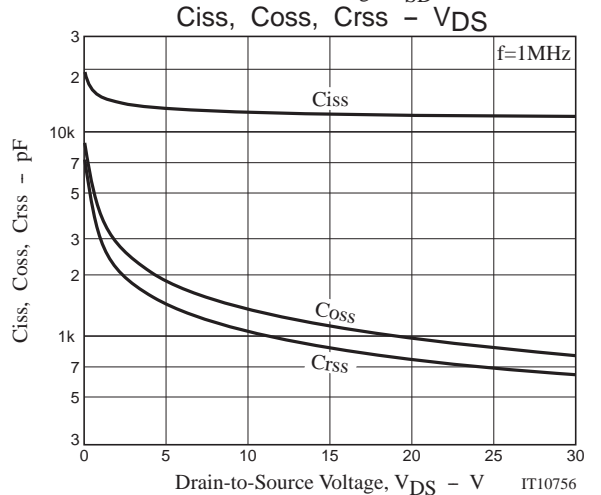
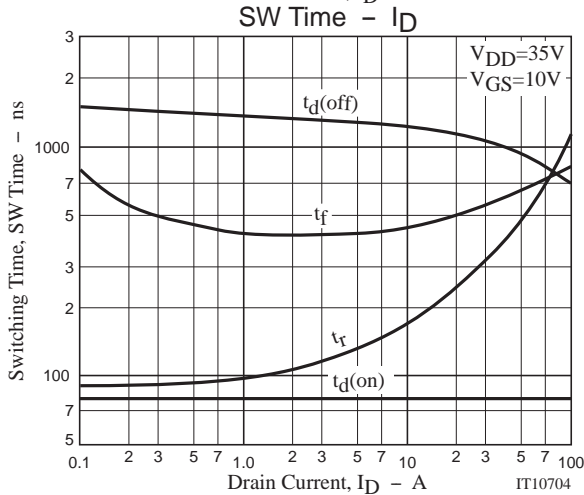
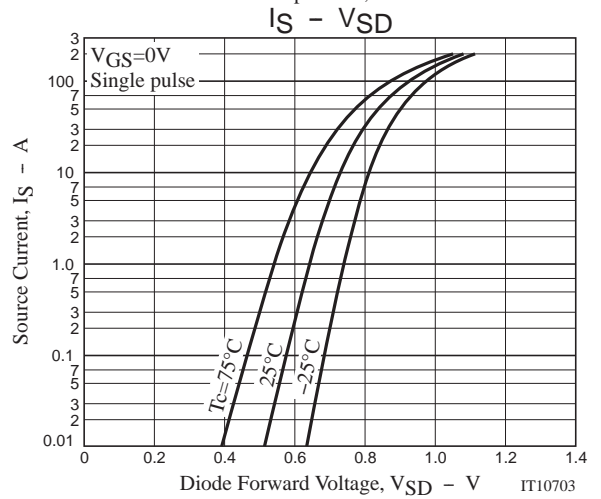
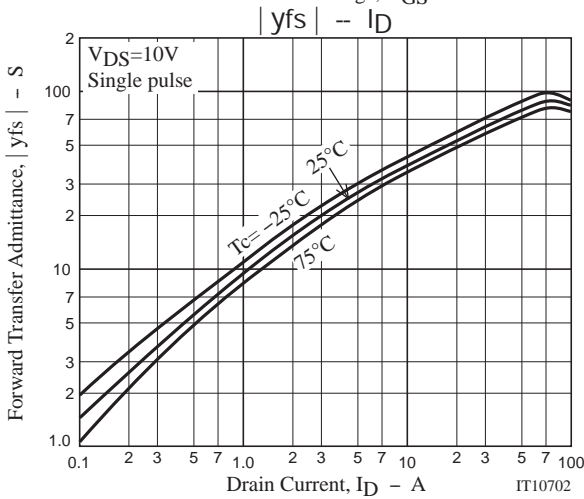
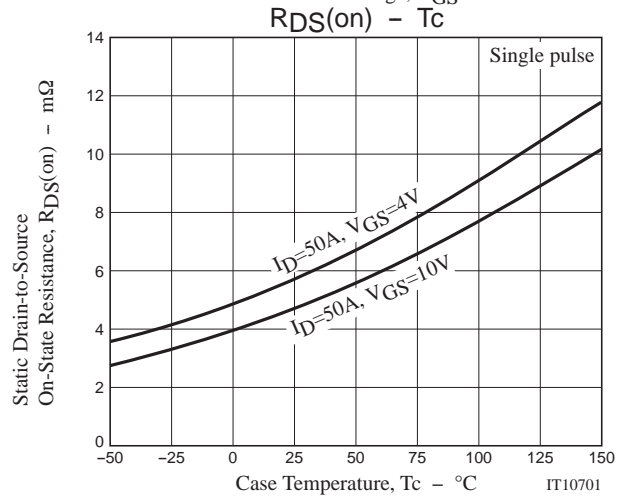
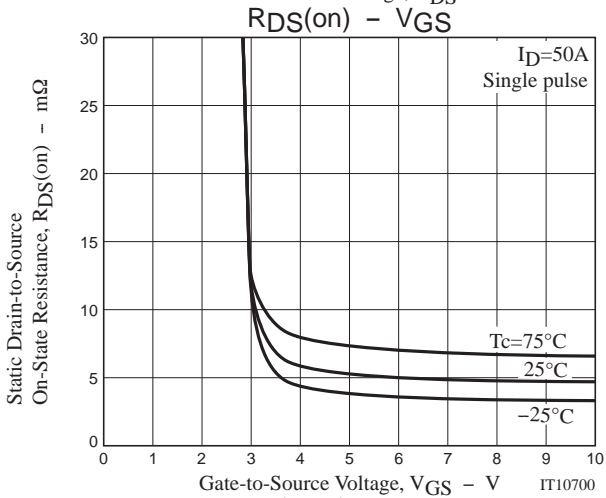
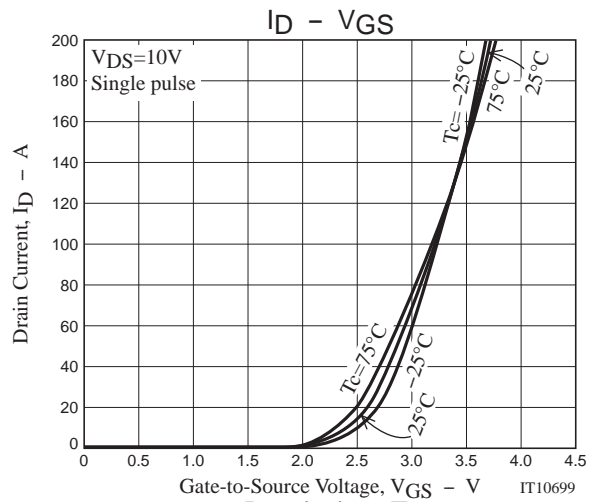
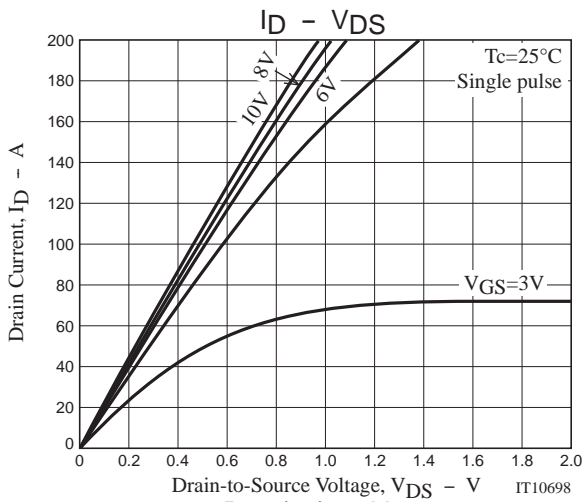


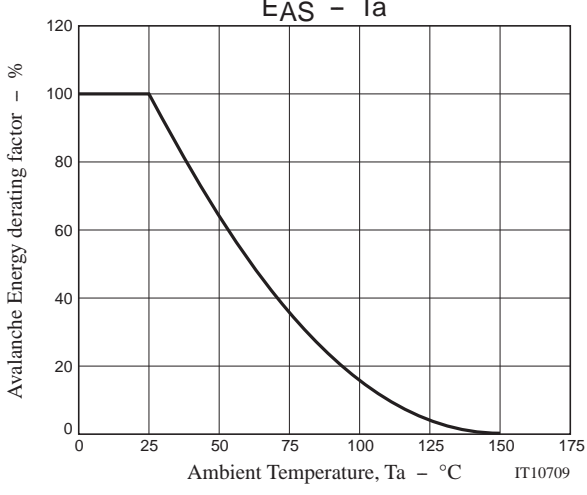
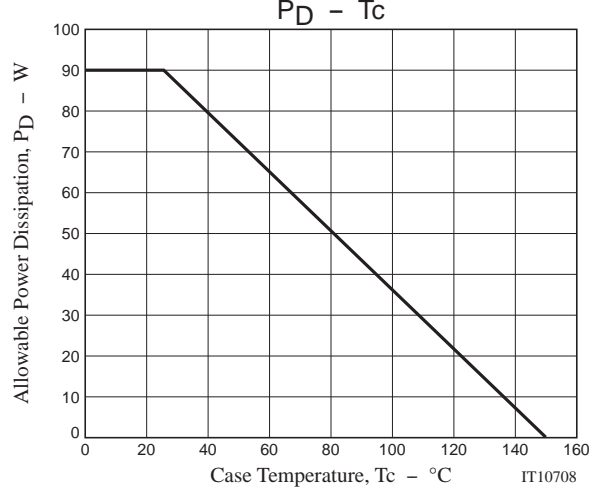
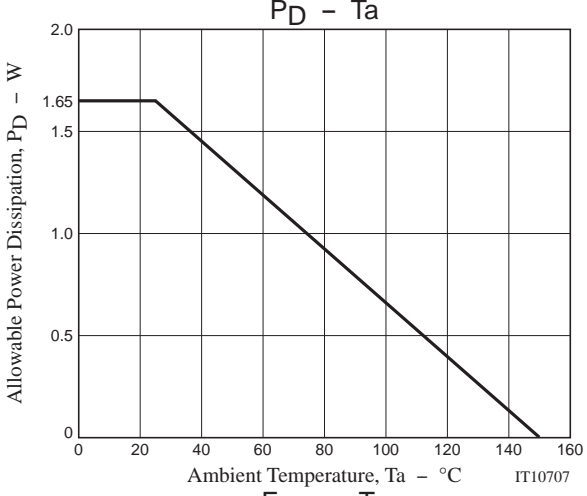
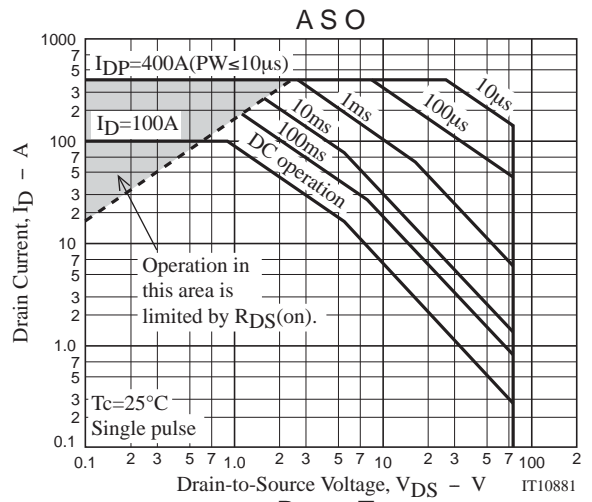
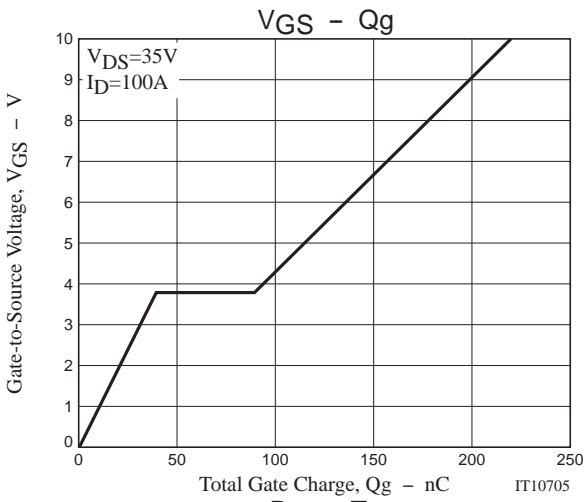
Fig.2 Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
2SK4065-DL-1E	TO-263-2L	800pcs./reel	Pb Free





Taping Specification

2SK4065-DL-1E

1. Packing Format

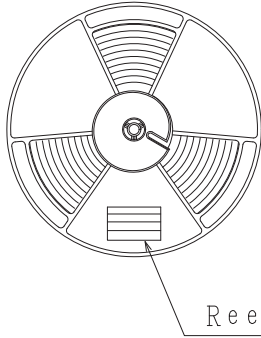
Package Name	Maximum Number of devices contained (pcs)			Packing format	
	Reel	Inner box	Outer box	Inner BOX	Outer BOX
TO-263-2L	800	1600	6400	SPD-0V0011 2 reel contained Dimensions:mm (external) 351×340×68	SPD-0V0009 4 inner boxes contained Dimensions:mm (external) 390×370×318

Reel label, Inner box label

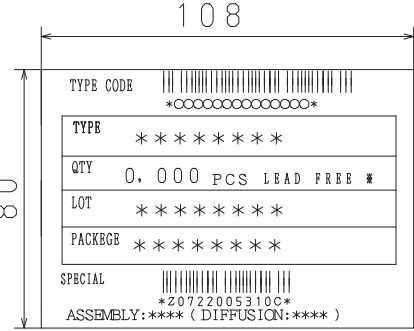
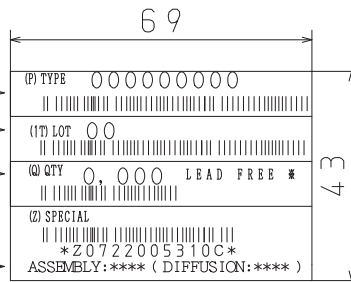
Outer box label

(unit:mm)

Packing method



Type No. →
LOT No. →
Quantity →
Origin →
Reel label



It is a label at the time of factory shipments. The form of a label may change in physical distribution process.

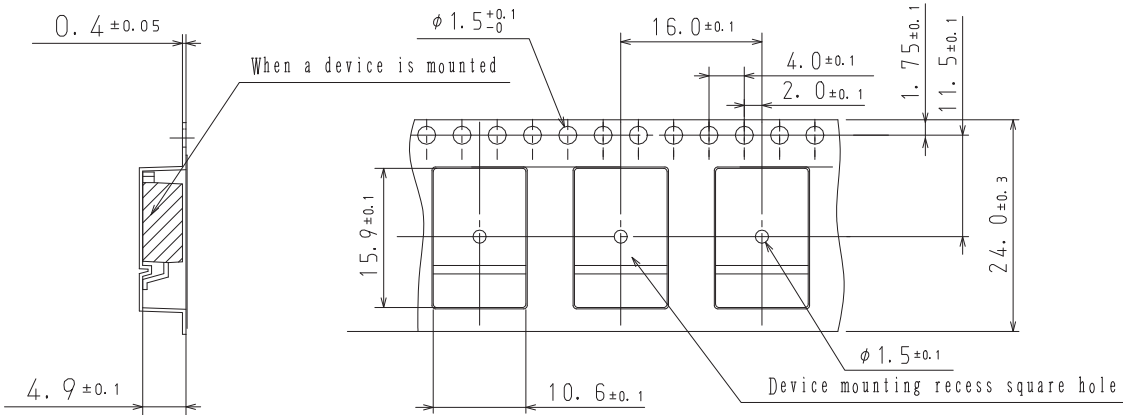
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

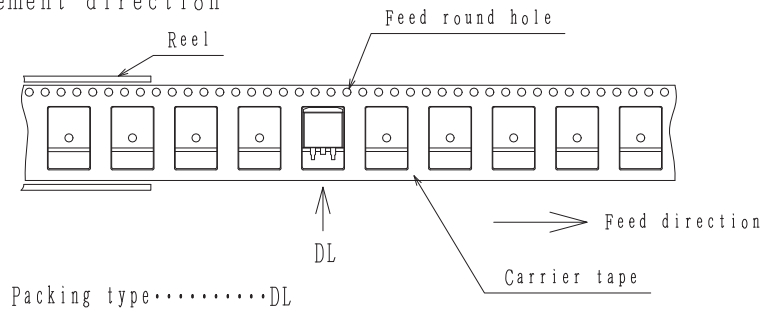
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A

2. Taping configuration

2-1. Carrier tape size (unit:mm)



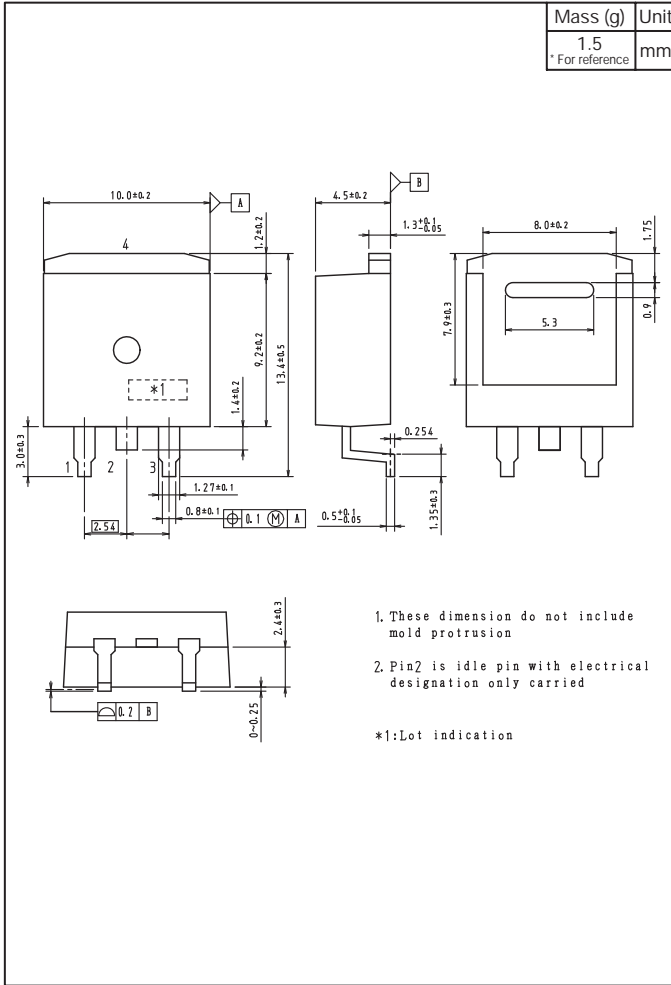
2-2. Device placement direction



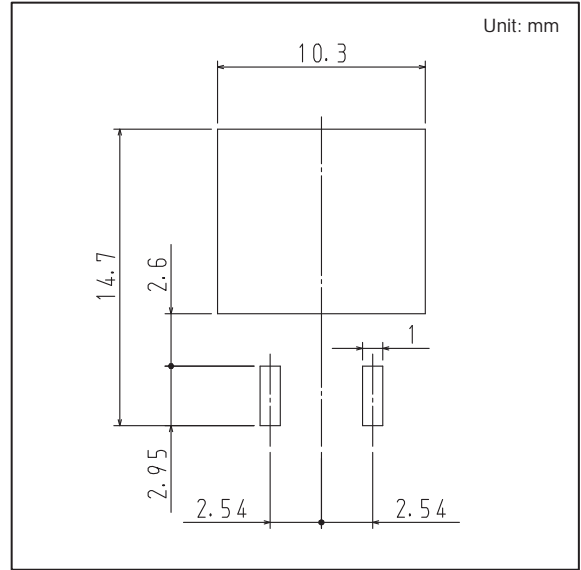
2SK4065

Outline Drawing

2SK4065-DL-1E



Land Pattern Example



Note on usage : Since the 2SK4065 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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